





P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
-30V	$13m\Omega @ V_{GS} = -10V$	-9.8A
	$25m\Omega$ @ $V_{GS} = -4.5V$	-7.0A

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses Are Minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

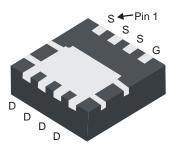
- Case: POWERDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0174 grams (Approximate)

POWERDI3333-8

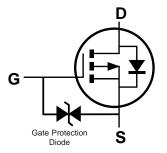








Bottom View



Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMG7401SFGQ-7	POWERDI3333-8	2,000/Tape & Reel
DMG7401SFGQ-13	POWERDI3333-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



G75 = Product Marking Code YYWW = Date Code Marking
YY = Last Digit of Year (ex: 10 for 2010)
WW = Week Code (01 – 53)

Characteristic	Symbol	Value	Units			
Drain-Source Voltage	V_{DSS}	-30	V			
Gate-Source Voltage			V _{GSS}	±25	V	
Continuous Pusin Comment (Note 7) // 40/	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	-9.8 -7.7	А	
Continuous Drain Current (Note 7) V _{GS} = -10V		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-13.5 -10.8	А	
Maximum Continuous Body Diode Forward Curren	Is	-3.0	Α			
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	-80	Α	
Avalanche Current (Notes 8 & 9)			I _{AR}	14	Α	
Repetitive Avalanche Energy (Notes 8 & 9) L = 1mH			E _{AR}	104	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Power Dissipation (Note 6)	T _A = +25°C	P _D	0.94	W	
Total Power Dissipation (Note 6)	T _A = +70°C		0.6	VV	
Thermal Desigtance, Junction to Ambient (Note 6)	Steady State	D	137	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	82	°C/W	
Total Dawer Dissination (Note 7)	T _A = +25°C	-	2.2	W	
Total Power Dissipation (Note 7)	T _A = +70°C	P_D	1.3		
Thermal Peciatones Junction to Ambient (Note 7)	Steady State	D	60	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)	t<10s	$R_{\theta JA}$	36	°C/W	
Thermal Resistance, Junction to Case (Note 7)		R ₀ JC	3.0	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
- 8. I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep $T_{J} = +25$ °C.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

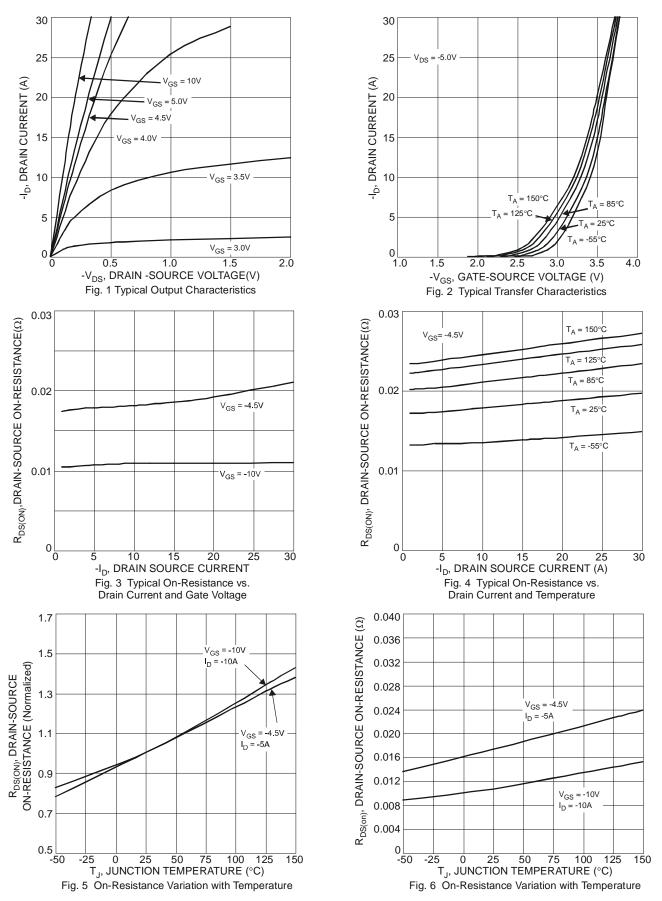
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V$, $I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS		_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	-1.7	_	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
		_	9	11		$V_{GS} = -20V, I_D = -12A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	10	13	mΩ	$V_{GS} = -10V, I_D = -9A$	
		1	17	25		$V_{GS} = -4.5V, I_D = -5A$	
Forward Transfer Admittance	Y _{fs}	l	21	_	S	$V_{DS} = -5V, I_{D} = -10A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	-	2,246	2,987	pF	15)/)/ 0)/	
Output Capacitance	Coss	1	352	468	pF	$V_{DS} = -15V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C_{rss}	l	294	391	pF	1 = 1.0MHZ	
Gate resistance	R_g	1	5.1	10	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_g	1	20.5	30	nC		
Total Gate Charge (V _{GS} = 10V)	Q_g	I	41	58	nC	\/ 45\/ L 42A	
Gate-Source Charge	Q_{gs}	1	7.6	_	nC	$V_{DS} = -15V, I_{D} = -12A$	
Gate-Drain Charge	Q_{gd}	_	8.0	_	nC		
Turn-On Delay Time	t _{D(on)}	_	11.3	23	nS		
Turn-On Rise Time	t _r	_	15.4	31	nS	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	t _{D(off)}	_	38.0	61	nS	$R_L = 1.25\Omega$, $R_G = 3\Omega$,	
Turn-Off Fall Time	t _f	_	22.0	38	nS		
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V_{SD}	I	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
Reverse Recovery Time (Note 10)	t _{rr}	_	20	31	nS		
Reverse Recovery Charge (Note 10)	Q _{rr}	-	9.5	18	nC	I _S = -9.5A, dl/dt = 100A/μs	

Notes:

^{9.} Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.









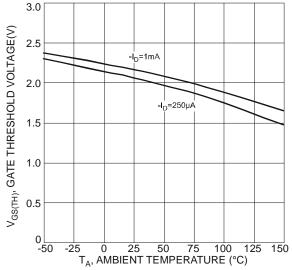
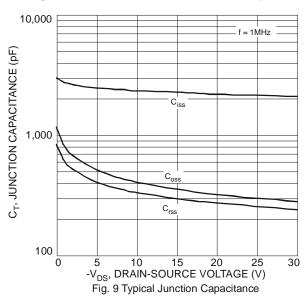
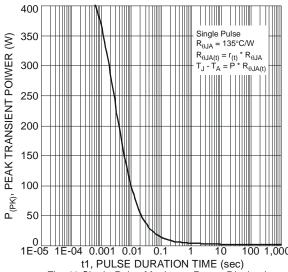
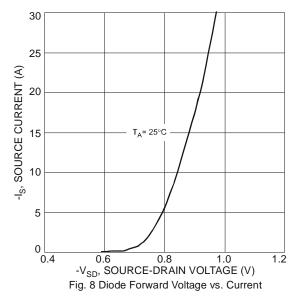


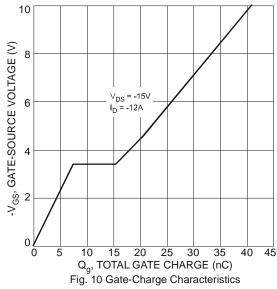
Fig. 7 Gate Threshold Variation vs. Ambient Temperature

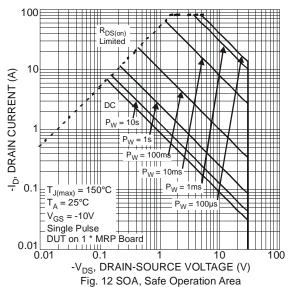




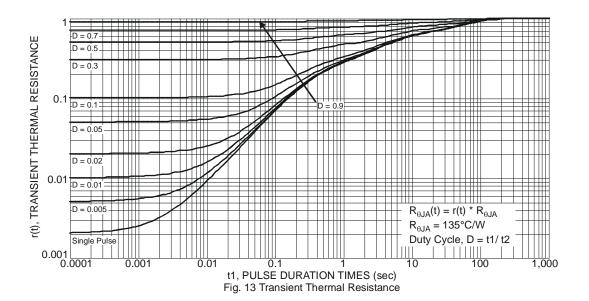
t1, PULSE DURATION TIME (sec)
Fig. 11 Single Pulse Maximum Power Dissipation









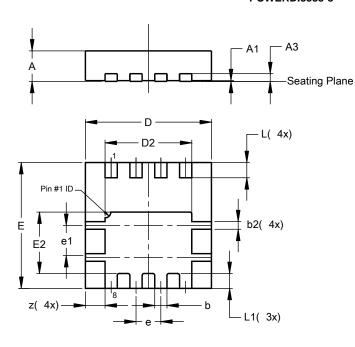




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

POWERDI3333-8

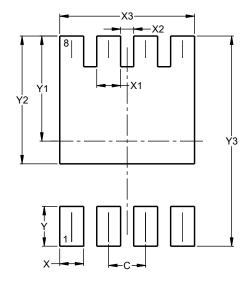


POWERDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	_	0.203			
b	0.27	0.37	0.32			
b2	-	_	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
е	_	-	0.65			
e1	0.79	0.89	0.84			
L	0.35	0.45	0.40			
L1		_	0.39			
Z	_	_	0.515			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

POWERDI3333-8



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700



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